

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low $V_{\mbox{\scriptsize F}}$
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

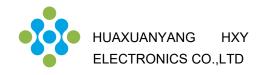
Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Marking]
HC1D06065N	QPFN5X6	HC1D06065N	



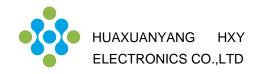




Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	650	V	
Surge Peak Reverse Voltage	V _{RSM}	650	V	
DC Peak Reverse Voltage	V _R	650	V	
Continuous Forward Current $T_c = 25^{\circ}C$ $T_c = 135^{\circ}C$ $T_c = 162^{\circ}C$	I _F	23 12 6	A	
Repetitive Peak Forward Surge Current $T_{c} = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $T_{c} = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	I _{FRM}	28 17	A	
Non-Repetitive Forward Surge Current $T_{c} = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $T_{c} = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	I _{FSM}	48 43	A	
i^{2} dt value T _C = 25°C,t _p =10ms,Half Sine Pulse T _C = 110°C,t _p =10ms,Half Sine Pulse	∫i²dt	11.4 9.1	A ² s	
Power dissipation $T_{C} = 25^{\circ}C$ $T_{C} = 110^{\circ}C$	P _{tot}	71 30	w	
Operating junction Range	Tj	-55 to +175	°C	
Storage temperature Range	T _{stg}	-55 to +150	°C	

Thermal Resistance

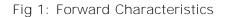
Parameter	Symbol	Тур.	Unit
Thermal resistance, junction – case.	R_{thJC}	2.10	°C/W



Parameter	Symbol	Value			Unit	Test Condition
	Symbol	min.	typ.	max.	Unit	Test Condition
Forward Voltage	V _F				V	I _F =6A
		-	1.3	1.5		T _j =25°C
		-	1.5			Т _ј =175°С
Reverse Current	I _R					V _R =650V
		-	-	50	μA	T _j =25°C
		-	-	200		T _j =175°C
Total Capacitive Charge	Q _c	-	18	-	nC	V _R =400V, T _j =25℃
						$V_{R} = 400V, T_{j} = 25°C$ $Q_{C} = \int_{0}^{V_{R}} C(V) dV$
Total Capacitance	С				pF	T _j =25℃, f=1MHz
		-	358	-		V _R =0V
		-	36	-		V _R =200V
		-	30	-		V _R =400V

Electrical Characteristic (at Tc = 25 °C, unless otherwise specified)

Characteristics Curve



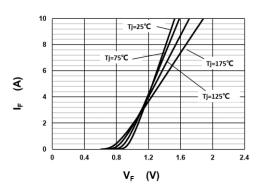


Fig 2: Reverse Characteristics

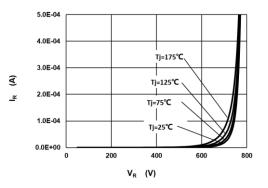




Fig 3: Current Derating

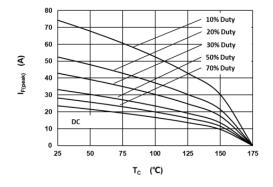
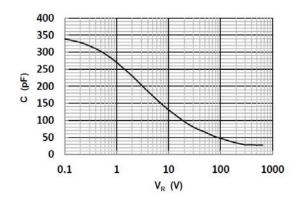


Fig 5: Capacitance vs. Reverse Voltage



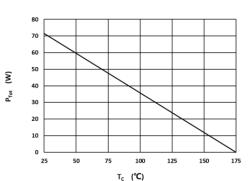


Fig 4: Power Derating

Fig 6: Reverse Charge vs. Reverse Voltage

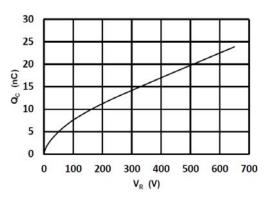
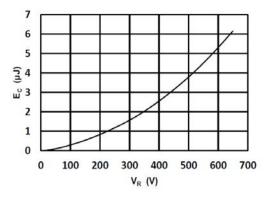
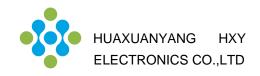


Fig 7: Typical Capacitance Stored Energy





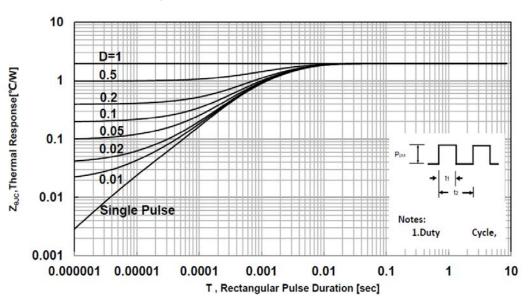
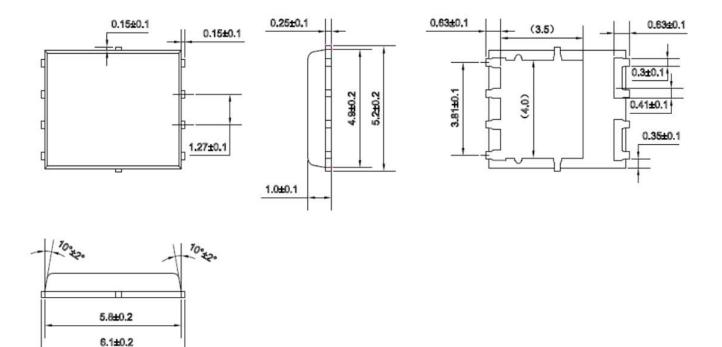


Fig 8: Transient Thermal Impandance



Package Dimensions

Package PQFN5X6





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